

## 1- Problem Description :

The present study reports numerical simulation of natural convection cooling of a heat source (representing power-dissipating semiconductor devices in electronics /MEMS applications) embedded on the lower wall of a square cavity filled with thermo-dependent fluids. The heat source produces a constant heat flux. The rest of the bottom wall and the top wall are adiabatic while the vertical ones are kept at a relatively low temperature (figure1).

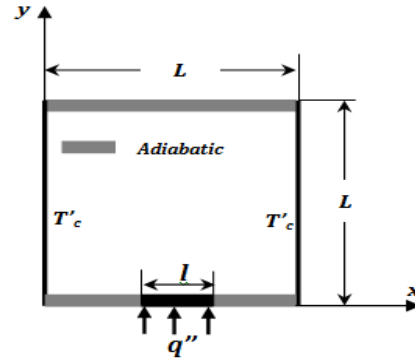


Figure 1: Sketch of the Cavity

The problem satisfies the following conditions:

- The fluid is “almost” incompressible and satisfies the Boussinesq approximation.
- All other thermodynamic and transport properties of the fluid, except for viscosity, are constant with respect to temperature.
- The Z dimension is much greater than the X and Y dimensions and thus the problem can be considered as essentially two-dimensional.

## 2- Governing equations :

The dimensionless governing equations written in terms of velocity vector components, ( $U$ ,  $V$ ), pressure,  $P$ , and temperature,  $T$ , in Cartesian coordinate system ( $X$ ,  $Y$ ), are:

$$\frac{\partial U}{\partial X} + \frac{\partial V}{\partial Y} = 0$$

$$U \frac{\partial U}{\partial X} + V \frac{\partial U}{\partial Y} = -\frac{\partial P}{\partial X} + Pr \left[ \mu \left( \frac{\partial^2 U}{\partial X^2} + \frac{\partial^2 U}{\partial Y^2} \right) + 2 \frac{\partial \mu}{\partial X} \frac{\partial U}{\partial X} + \frac{\partial \mu}{\partial Y} \left( \frac{\partial U}{\partial Y} + \frac{\partial V}{\partial X} \right) \right]$$

$$U \frac{\partial V}{\partial X} + V \frac{\partial V}{\partial Y} = -\frac{\partial P}{\partial Y} + Pr \left[ \mu \left( \frac{\partial^2 V}{\partial X^2} + \frac{\partial^2 V}{\partial Y^2} \right) + 2 \frac{\partial \mu}{\partial Y} \frac{\partial V}{\partial Y} + \frac{\partial \mu}{\partial X} \left( \frac{\partial U}{\partial Y} + \frac{\partial V}{\partial X} \right) + RaT \right]$$

$$U \frac{\partial T}{\partial X} + V \frac{\partial T}{\partial Y} = \frac{\partial^2 T}{\partial X^2} + \frac{\partial^2 T}{\partial Y^2}$$

$$\mu = \exp(-mT)$$

## 3- Objective and method used to solve the problem :

the main purpose of the present work is to examine the effects of control parameters, which are Rayleigh ( $Ra$ ) and Pearson ( $m$ ) numbers on the fluid flow and the resulting heat transfer. In this study finite volume method is used method in a staggered grid system to solve The governing partial differential equations through iterative Semi Implicit Method for Pressure Linked Equation (SIMPLE) algorithm.

## 4- Results :

Figure 2 displays the average Nusselt number at the heated surface , for different values of Rayleigh ( $Ra$ ) and Pearson ( $m$ ) numbers.

It is clear that the increase in Rayleigh number causes the average Nusselt number to decrease because of the strengthening of buoyancy forces in comparison to viscous forces. Moreover, The increase in  $m$  leads to the enhancement of the convection process, which is reflected in the rise of the average Nusselt due to the weakening of apparent viscosity as  $m$  increases.

Since a poor convection is formed inside the enclosure at  $Ra = 10^3$ , the Pearson has only a negligible effect on average Nusselt number.

## 5- Conclusion :

- the average Nusselt number increases with increasing Rayleigh number due to the strengthening of convective transport.
- The rise of  $m$  reduces the apparent viscosity of the fluid, which leads to an enhancement in convection transport due to weakening of resistance to the fluid motion offered by the fluid viscosity.

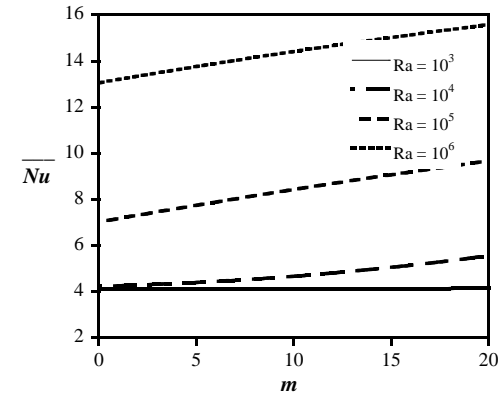


Figure 2: average Nusselt number for different values of Rayleigh and Pearson number